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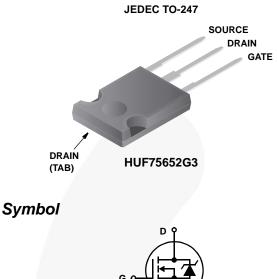
HUF75652G3

Data Sheet

October 2013

N-Channel UltraFET Power MOSFET 100 V, 75 A, 8 mΩ

Packaging



Features

• Ultra Low On-Resistance

- $r_{DS(ON)} = 0.008\Omega, V_{GS} = 10V$

- Simulation Models
 - Temperature Compensated PSPICE® and SABER™ Electrical Models
 - Spice and SABER Thermal Impedance Models
 - www.fairchildsemi.com
- Peak Current vs Pulse Width Curve
- UIS Rating Curve

Ordering Information

PART NUMBER	PACKAGE	BRAND
HUF75652G3	TO-247	75652G

Absolute Maximum Ratings	$T_{C} = 25^{\circ}C$, Unless Otherwise Specified
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	HUF75652G3	UNITS
Drain to Source Voltage (Note 1)	100	V
Drain to Gate Voltage ($R_{GS} = 20k\Omega$) (Note 1)	100	V
Gate to Source Voltage V _{GS}	±20	V
$ \begin{array}{c} \text{Drain Current} \\ \text{Continuous } (T_{C} = 25^{o}C, V_{GS} = 10V) (\text{Figure 2}) \ldots & I_{D} \\ \text{Continuous } (T_{C} = 100^{o}C, V_{GS} = 10V) (\text{Figure 2}) \ldots & I_{D} \\ \text{Pulsed Drain Current} & I_{DM} \end{array} $	75 75 Figure 4	A A
Pulsed Avalanche Rating UIS	Figure 6	
Power Dissipation (Note 2) PD Derate Above 25 ^o C	515 3.44	W W/ ^o C
Operating and Storage Temperature	-55 to 175	°C
Maximum Temperature for Soldering Leads at 0.063in (1.6mm) from Case for 10sT _L Package Body for 10s, See Techbrief TB334T _{pkg}	300 260	°C °C
NOTES:		

1. $T_J = 25^{\circ}C$ to $150^{\circ}C$.

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

Product reliability information can be found at http://www.fairchildsemi.com/products/discrete/reliability/index.html For severe environments, see our Automotive HUFA series.

All Fairchild semiconductor products are manufactured, assembled and tested under ISO9000 and QS9000 quality systems certification.

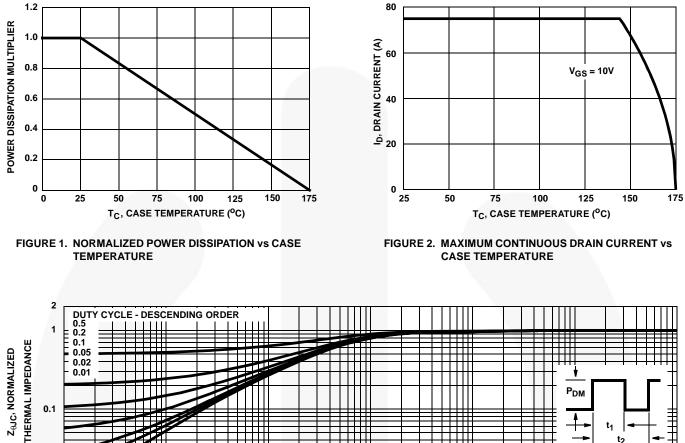
PARAMETER	SYMBOL	TEST CONDITIONS		MIN	ТҮР	MAX	UNITS
OFF STATE SPECIFICATIONS		I		J		1	<u></u>
Drain to Source Breakdown Voltage	BV _{DSS}	$I_D = 250\mu A$, $V_{GS} = 0V$ (Figure 11)		100	-	-	V
Zero Gate Voltage Drain Current	IDSS	V _{DS} = 95V, V _{GS} = 0V		-	-	1	μΑ
		$V_{DS} = 90V, V_{GS} = 0V, T_{C} = 150^{\circ}C$		-	-	250	μA
Gate to Source Leakage Current	I _{GSS}	$V_{GS} = \pm 20V$		-	-	±100	nA
ON STATE SPECIFICATIONS	1				-	L	
Gate to Source Threshold Voltage	V _{GS(TH)}	$V_{GS} = V_{DS}, I_D = 250$	0μA (Figure 10)	2	-	4	V
Drain to Source On Resistance	rDS(ON)	I _D = 75A, V _{GS} = 10V	/ (Figures 9)	-	0.0067	0.008	Ω
THERMAL SPECIFICATIONS						L	
Thermal Resistance Junction to Case	R _{θJC}	TO-247		-	-	0.29	°C/W
Thermal Resistance Junction to Ambient	R _{θJA}			-	-	30	°C/W
SWITCHING SPECIFICATIONS (V_{GS} =	= 10V)			L.			
Turn-On Time	ton	V_{DD} = 50V, I _D = 75A, V_{GS} = 10V, R_{GS} = 2.0 Ω		-	-	320	ns
Turn-On Delay Time	t _{d(ON)}	_		-	18.5	-	ns
Rise Time	t _r			-	195	-	ns
Turn-Off Delay Time	t _{d(OFF)}			-	80	-	ns
Fall Time	t _f			-	190	-	ns
Turn-Off Time	tOFF			-	-	410	ns
GATE CHARGE SPECIFICATIONS	1				-		
Total Gate Charge	Q _{g(TOT)}	$V_{GS} = 0V$ to 20V	$V_{DD} = 50V,$	-	393	475	nC
Gate Charge at 10V	Q _{g(10)}	$V_{GS} = 0V$ to 10V	☐ I _D = 75A, I _{g(REF)} = 1.0mA (Figure 13)	/ -	211	255	nC
Threshold Gate Charge	Q _{g(TH)}	$V_{GS} = 0V$ to 2V		-	14	16.5	nC
Gate to Source Gate Charge	Q _{gs}				26	-	nC
Gate to Drain "Miller" Charge	Q _{gd}			-	74	-	nC
CAPACITANCE SPECIFICATIONS							
Input Capacitance	C _{ISS}	$V_{DS} = 25V, V_{GS} = 0$	V,	-	7585	-	pF
Output Capacitance	C _{OSS}	f = 1MHz (Figure 12)		-	2345	-	pF
Reverse Transfer Capacitance	C _{RSS}			-	630		pF

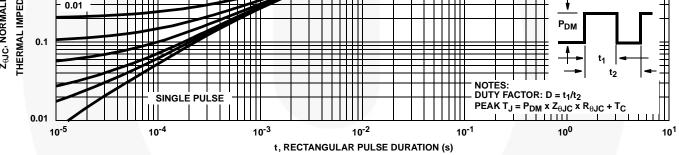
Electrical Specifications $T_C = 25^{\circ}C$, Unless Otherwise Specified

Source to Drain Diode Specifications

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	ТҮР	MAX	UNITS
Source to Drain Diode Voltage	V _{SD}	I _{SD} = 75A	-	-	1.25	V
		I _{SD} = 35A	-	-	1.00	V
Reverse Recovery Time	t _{rr}	I _{SD} = 75A, dI _{SD} /dt = 100A/μs	-	-	150	ns
Reverse Recovered Charge	Q _{RR}	I _{SD} = 75A, dI _{SD} /dt = 100A/μs	-	-	490	nC

Typical Performance Curves







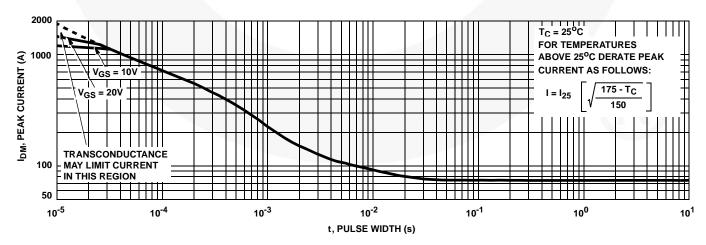


FIGURE 4. PEAK CURRENT CAPABILITY

Typical Performance Curves (Continued)

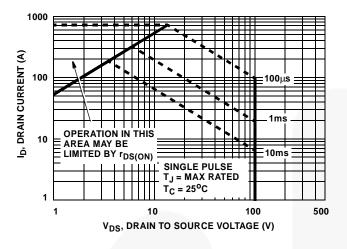


FIGURE 5. FORWARD BIAS SAFE OPERATING AREA

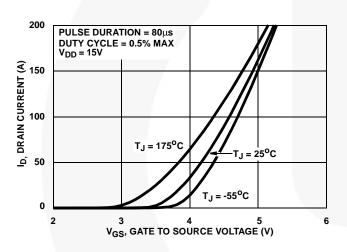
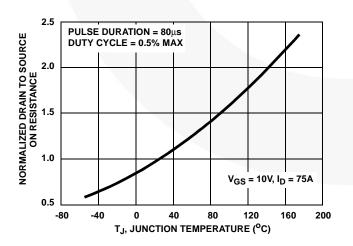
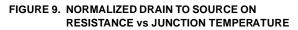
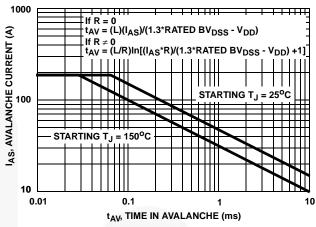


FIGURE 7. TRANSFER CHARACTERISTICS







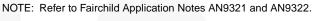


FIGURE 6. UNCLAMPED INDUCTIVE SWITCHING CAPABILITY

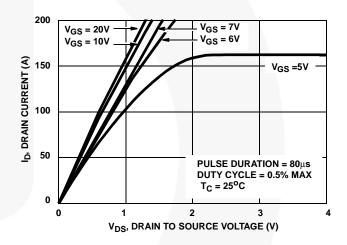
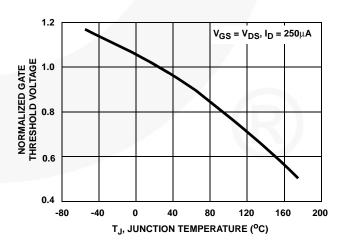
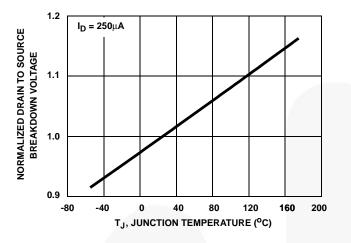


FIGURE 8. SATURATION CHARACTERISTICS

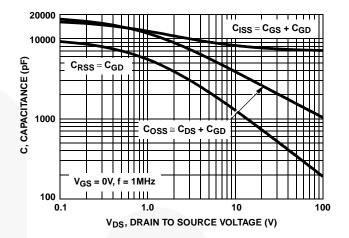




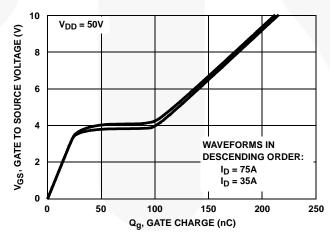
Typical Performance Curves (Continued)













Test Circuits and Waveforms

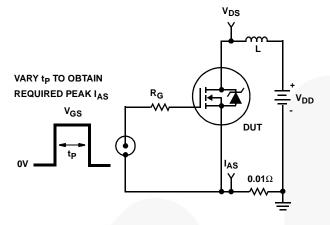


FIGURE 14. UNCLAMPED ENERGY TEST CIRCUIT

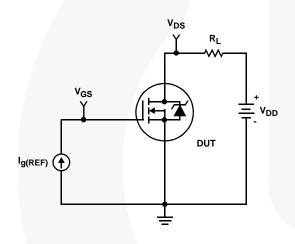


FIGURE 16. GATE CHARGE TEST CIRCUIT

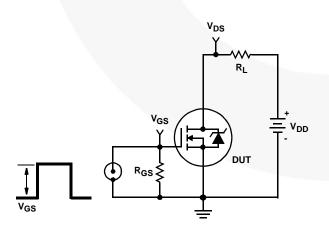


FIGURE 18. SWITCHING TIME TEST CIRCUIT

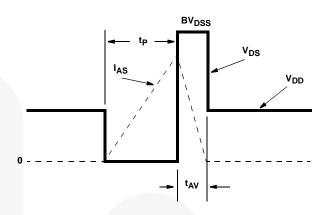
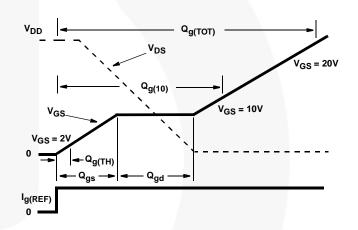


FIGURE 15. UNCLAMPED ENERGY WAVEFORMS





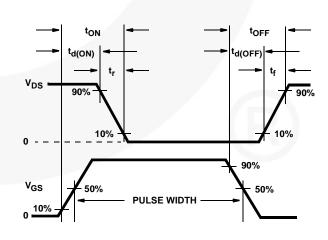
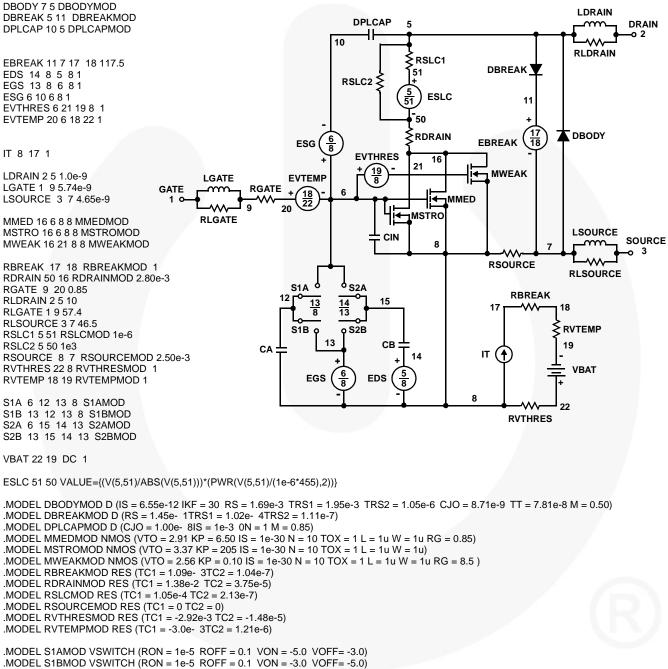


FIGURE 19. SWITCHING TIME WAVEFORM

PSPICE Electrical Model

.SUBCKT HUF75652 2 1 3 ; rev 11 May 1999

CA 12 8 11.0e-9 CB 15 14 11.4e-9 CIN 6 8 6.95e-9

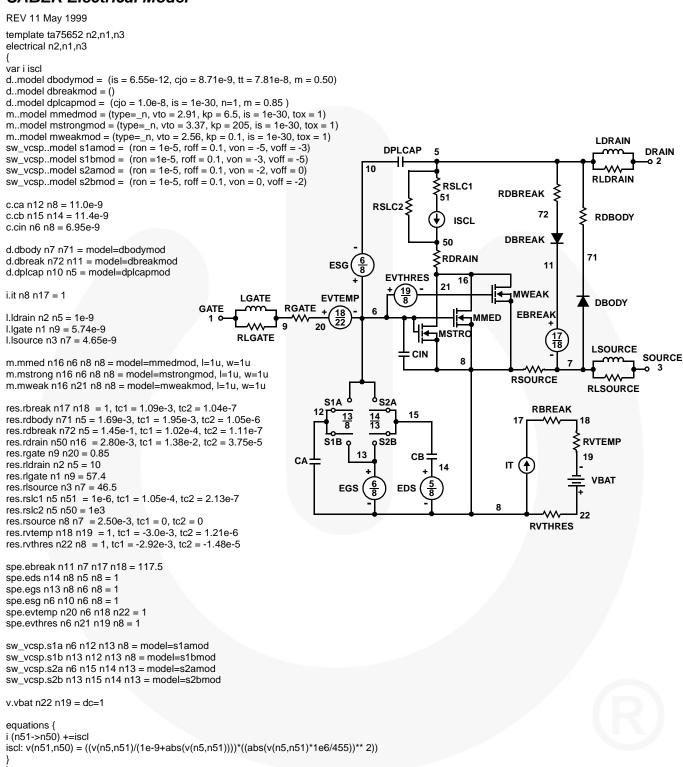


.MODEL S2AMOD VSWITCH (RON = 1e-5 ROFF = 0.1 VON = -2.0 VOFF = 0.0) .MODEL S2BMOD VSWITCH (RON = 1e-5 ROFF = 0.1 VON = 0.0 VOFF = -2.0)

.ENDS

NOTE: For further discussion of the PSPICE model, consult **A New PSPICE Sub-Circuit for the Power MOSFET Featuring Global Temperature Options**; IEEE Power Electronics Specialist Conference Records, 1991, written by William J. Hepp and C. Frank Wheatley.

SABER Electrical Model



SPICE Thermal Model

REV 1April 1999

HUF75652T

CTHERM1 th 6 9.75e-3 CTHERM2 6 5 3.90e-2 CTHERM3 5 4 2.50e-2 CTHERM4 4 3 2.95e-2 CTHERM5 3 2 6.55e-2 CTHERM6 2 tl 12.55

RTHERM1 th 6 1.96e-3 RTHERM2 6 5 4.89e-3 RTHERM3 5 4 1.38e-2 RTHERM4 4 3 7.73e-2 RTHERM5 3 2 1.17e-1 RTHERM6 2 tl 1.55e-2

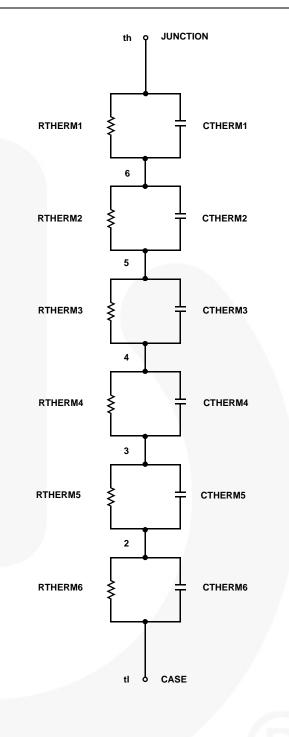
SABER Thermal Model

SABER thermal model HUF75652T

template thermal_model th tl thermal_c th, tl

ctherm.ctherm1 th 6 = 9.75e-3ctherm.ctherm2 6 = 3.90e-2ctherm.ctherm3 5 = 42.50e-2ctherm.ctherm4 4 = 2.50e-2ctherm.ctherm5 3 = 2.95e-2ctherm.ctherm5 3 = 2.95e-2ctherm.ctherm6 2 = 12.55

rtherm.rtherm1 th 6 = 1.96e-3 rtherm.rtherm2 6 5 = 4.89e-3 rtherm.rtherm3 5 4 = 1.38e-2 rtherm.rtherm4 4 3 = 7.73e-2 rtherm.rtherm5 3 2 = 1.17e-1 rtherm.rtherm6 2 tl = 1.55e-2 }



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